

54AC/74AC175 • 54ACT/74ACT175

Quad D Flip-Flop

General Description

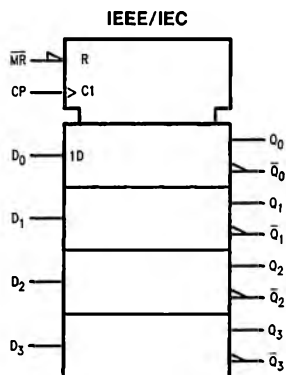
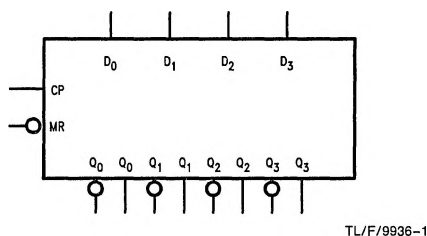
The 'AC/'ACT175 is a high-speed quad D flip-flop. The device is useful for general flip-flop requirements where clock and clear inputs are common. The information on the D inputs is stored during the LOW-to-HIGH clock transition. Both true and complemented outputs of each flip-flop are provided. A Master Reset input resets all flip-flops, independent of the Clock or D inputs, when LOW.

Features

- Edge-triggered D-type inputs
- Buffered positive edge-triggered clock
- Asynchronous common reset
- True and complement output
- Outputs source/sink 24 mA
- 'ACT175 has TTL-compatible inputs
- Standard Military Drawing (SMD)
 - 'AC175: 5962-89552
 - 'ACT175: 5962-89693

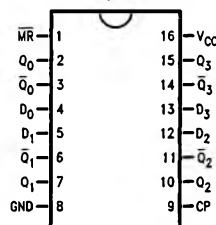
Ordering Code: See Section 8

Logic Symbols

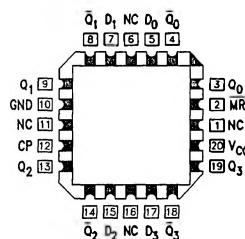


Connection Diagrams

**Pin Assignment
for DIP, Flatpak and SOIC**



**Pin Assignment
for LCC**



Pin Names	Description
D ₀ –D ₃	Data Inputs
CP	Clock Pulse Input
MR	Master Reset Input
Q ₀ –Q ₃	True Outputs
Q ₀ –Q ₃	Complement Outputs

Functional Description

The 'AC/'ACT175 consists of four edge-triggered D flip-flops with individual D inputs and Q and $\bar{Q}$ outputs. The Clock and Master Reset are common. The four flip-flops will store the state of their individual D inputs on the LOW-to-HIGH clock (CP) transition, causing individual Q and $\bar{Q}$ outputs to follow. A LOW input on the Master Reset ($\overline{MR}$) will force all Q outputs LOW and $\bar{Q}$ outputs HIGH independent of Clock or Data inputs. The 'AC/'ACT175 is useful for general logic applications where a common Master Reset and Clock are acceptable.

Truth Table

Inputs		Outputs	
@ t_n , $\overline{MR} = H$		@ t_{n+1}	
D_n		Q_n	$\bar{Q}_n$
L		L	H
H		H	L

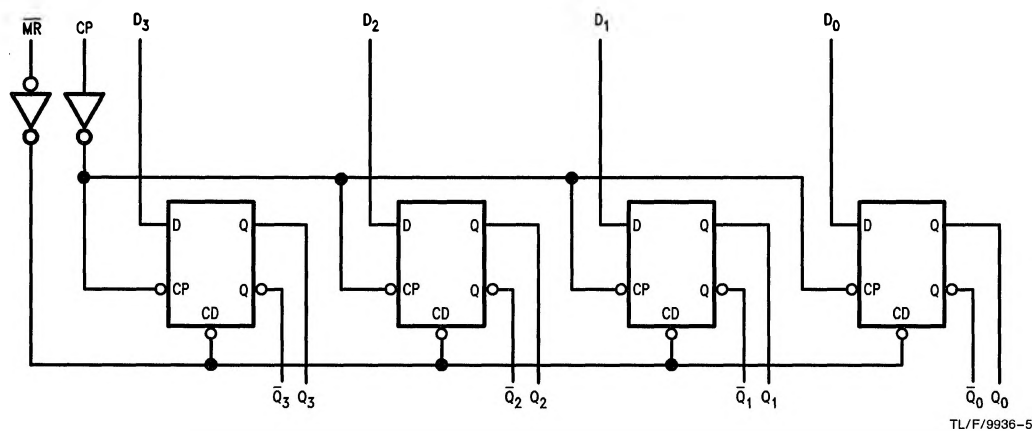
H = HIGH Voltage Level

L = LOW Voltage Level

t_n = Bit Time before Clock Pulse

t_{n+1} = Bit Time after Clock Pulse

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{CC})	-0.5V to +7.0V
DC Input Diode Current (I_{IK})	
$V_I = -0.5V$	-20 mA
$V_I = V_{CC} + 0.5V$	+20 mA
DC Input Voltage (V_I)	-0.5V to $V_{CC} + 0.5V$
DC Output Diode Current (I_{OK})	
$V_O = -0.5V$	-20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V_O)	-0.5V to $V_{CC} + 0.5V$
DC Output Source or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	-65°C to +150°C
Junction Temperature (T_J)	
CDIP	175°C
PDIP	140°C

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation of FACT™ circuits outside databook specifications.

Recommended Operating Conditions

Supply Voltage (V_{CC})	
'AC	2.0V to 6.0V
'ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	
74AC/ACT	-40°C to +85°C
54AC/ACT	-55°C to +125°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
'AC Devices	
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
'ACT Devices	
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	125 mV/ns

DC Characteristics for 'AC Family Devices

Symbol	Parameter	V _{CC} (V)	74AC		54AC		74AC		Units	Conditions
			T _A = +25°C		T _A = −55°C to +125°C		T _A = −40°C to +85°C			
			Typ	Guaranteed Limits						
V _{IH}	Minimum High Level Input Voltage	3.0	1.5	2.1	2.1		2.1		V	V _{OUT} = 0.1V or V _{CC} − 0.1V
		4.5	2.25	3.15	3.15		3.15			
		5.5	2.75	3.85	3.85		3.85			
V _{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.9	0.9		0.9		V	V _{OUT} = 0.1V or V _{CC} − 0.1V
		4.5	2.25	1.35	1.35		1.35			
		5.5	2.75	1.65	1.65		1.65			
V _{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9		2.9		V	I _{OUT} = −50 μA
		4.5	4.49	4.4	4.4		4.4			
		5.5	5.49	5.4	5.4		5.4			
		3.0		2.56	2.4		2.46		V	*V _{IN} = V _{IL} or V _{IH} −12 mA I _{OH} −24 mA −24 mA
		4.5		3.86	3.7		3.76			
		5.5		4.86	4.7		4.76			
V _{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1		0.1		V	I _{OUT} = 50 μA
		4.5	0.001	0.1	0.1		0.1			
		5.5	0.001	0.1	0.1		0.1			
		3.0		0.36	0.50		0.44		V	*V _{IN} = V _{IL} or V _{IH} 12 mA I _{OL} 24 mA 24 mA
		4.5		0.36	0.50		0.44			
		5.5		0.36	0.50		0.44			
I _{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0		±1.0		μA	V _I = V _{CC} , GND

*All outputs loaded; thresholds on input associated with output under test.

†Maximum test duration 2.0 ms, one output loaded at a time.

DC Characteristics for 'AC Family Devices (Continued)

Symbol	Parameter	V _{CC} (V)	74AC		54AC	74AC	Units	Conditions
			T _A = +25°C		T _A = –55°C to +125°C	T _A = –40°C to +85°C		
			Typ	Guaranteed Limits				
I _{OLD}	†Minimum Dynamic Output Current	5.5			50	75	mA	V _{OLD} = 1.65V Max
I _{OHD}		5.5			–50	–75	mA	V _{OHD} = 3.85V Min
I _{CC}	Maximum Quiescent Supply Current	5.5		8.0	160.0	80.0	μA	V _{IN} = V _{CC} or GND

*All outputs loaded; thresholds on input associated with output under test.

†Maximum test duration 2.0 ms, one output loaded at a time.

Note: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

I_{CC} for 54AC @ 25°C is identical to 74AC @ 25°C.

DC Characteristics for 'ACT Family Devices

Symbol	Parameter	V _{CC} (V)	74ACT		54ACT	74ACT	Units	Conditions
			T _A = +25°C		T _A = –55°C to +125°C	T _A = –40°C to +85°C		
			Typ	Guaranteed Limits				
V _{IH}	Minimum High Level Input Voltage	4.5	1.5	2.0	2.0	2.0	V	V _{OUT} = 0.1V or V _{CC} – 0.1V
		5.5	1.5	2.0	2.0	2.0		
V _{IL}	Maximum Low Level Input Voltage	4.5	1.5	0.8	0.8	0.8	V	V _{OUT} = 0.1V or V _{CC} – 0.1V
		5.5	1.5	0.8	0.8	0.8		
V _{OH}	Minimum High Level Output Voltage	4.5	4.49	4.4	4.4	4.4	V	I _{OUT} = –50 μA
		5.5	5.49	5.4	5.4	5.4		
		4.5		3.86	3.70	3.76	V	*V _{IN} = V _{IL} or V _{IH} –24 mA I _{OH} –24 mA
		5.5		4.86	4.70	4.76		
V _{OL}	Maximum Low Level Output Voltage	4.5	0.001	0.1	0.1	0.1	V	I _{OUT} = 50 μA
		5.5	0.001	0.1	0.1	0.1		
		4.5		0.36	0.50	0.44	V	*V _{IN} = V _{IL} or V _{IH} 24 mA I _{OL} 24 mA
		5.5		0.36	0.50	0.44		
I _{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	±1.0	μA	V _I = V _{CC} , GND
I _{CC1}	Maximum I _{CC} /Input	5.5	0.6		1.6	1.5	mA	V _I = V _{CC} – 2.1V
I _{OLD}	†Minimum Dynamic Output Current	5.5			50	75	mA	V _{OLD} = 1.65V Max
I _{OHD}		5.5			–50	–75	mA	V _{OHD} = 3.85V Min
I _{CC}	Maximum Quiescent Supply Current	5.5		8.0	160.0	80.0	μA	V _{IN} = V _{CC} or GND

*All outputs loaded; thresholds on input associated with output under test.

†Maximum test duration 2.0 ms, one output loaded at a time.

Note: I_{CC} for 54ACT @ 25°C is identical to 74ACT @ 25°C.

AC Electrical Characteristics: See Section 2 for waveforms

Symbol	Parameter	V _{CC} * (V)	74AC			54AC		74AC		Units	Fig. No.
			T _A = +25°C C _L = 50 pF			T _A = −55°C to +125°C C _L = 50 pF		T _A = −40°C to +85°C C _L = 50 pF			
			Min	Typ	Max	Min	Max	Min	Max		
f _{max}	Maximum Clock Frequency	3.3 5.0	149 187	214 244		95 95		139 187		MHz	
t _{PLH}	Propagation Delay CP to Q _n or $\overline{Q}_n$	3.3 5.0	2.0 1.5	9.5 7.0	12.0 9.0	1.0 1.0	15.0 11.5	2.0 1.0	13.5 9.5	ns	2-3,4
t _{PHL}	Propagation Delay CP to Q _n or $\overline{Q}_n$	3.3 5.0	2.5 1.5	8.5 6.0	13.0 9.5	1.0 1.0	14.5 10.5	2.0 1.5	14.5 10.5	ns	2-3,4
t _{PLH}	Propagation Delay MR to Q _n	3.3 5.0	3.0 2.0	7.5 5.5	12.5 9.0	1.0 1.0	13.5 10.5	2.5 1.5	13.5 10.0	ns	2-3,4
t _{PHL}	Propagation Delay MR to $\overline{Q}_n$	3.3 5.0	3.0 2.0	8.5 6.0	11.0 8.5	1.0 1.0	15.0 11.0	2.5 1.5	12.5 9.0	ns	2-3,4

*Voltage Range 3.3 is 3.3V ± 0.3V

Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements: See Section 2 for waveforms

Symbol	Parameter	V _{CC} [*] (V)	74AC		54AC		74AC		Units	Fig. No.
			T _A = +25°C C _L = 50 pF		T _A = -55°C to +125°C C _L = 50 pF		T _A = -40°C to +85°C C _L = 50 pF			
			Typ	Guaranteed Minimum						
t _s	Setup Time, HIGH or LOW D _n to CP	3.3 5.0	2.0 1.0	4.5 3.0	5.0 3.5	4.5 3.0	ns	2-7		
t _h	Hold Time, HIGH or LOW D _n to CP	3.3 5.0	1.0 1.0	1.0 1.0	2.0 2.5	1.0 1.0	ns	2-7		
t _w	CP Pulse Width HIGH or LOW	3.3 5.0	2.5 2.0	4.5 3.5	6.0 5.0	4.5 3.5	ns	2-3		
t _w	MR Pulse Width, LOW	3.3 5.0	2.5 2.0	4.5 3.5	5.5 5.0	5.0 3.5	ns	2-3		
t _{rec}	Recovery Time MR to CP	3.3 5.0	-2.0 -1.0	0 0	1.5 1.5	0 0	ns	2-3,7		

*Voltage Range 3.3 is 3.3V ± 0.3V

Voltage Range 5.0 is 5.0V ± 0.5V

AC Electrical Characteristics: See Section 2 for waveforms

Symbol	Parameter	V _{CC} * (V)	74ACT			54ACT		74ACT		Units	Fig. No.
			T _A = +25°C C _L = 50 pF			T _A = -55°C to +125°C C _L = 50 pF		T _A = -40°C to +85°C C _L = 50 pF			
			Min	Typ	Max	Min	Max	Min	Max		
t _{max}	Maximum Clock Frequency	5.0	175	236		95		145		MHz	
t _{PLH}	Propagation Delay CP to Q _n or Q̄ _n	5.0	2.0	6.0	10.0	1.0	11.5	1.5	11.0	ns	2-3,4
t _{PHL}	Propagation Delay CP to Q _n or Q̄ _n	5.0	2.0	7.0	11.0	1.0	12.5	1.5	12.0	ns	2-3,4
t _{PLH}	Propagation Delay MR to Q _n	5.0	2.0	6.0	9.5	1.0	11.5	1.5	10.5	ns	2-3,4
t _{PHL}	Propagation Delay MR to Q̄ _n	5.0	2.0	5.5	9.5	1.0	11.0	1.5	10.5	ns	2-3,4

*Voltage Range 5.0 is 5.0V ± 0.5V

AC Operating Requirements: See Section 2 for waveforms

Symbol	Parameter	V _{CC} * (V)	74ACT		54ACT	74ACT	Units	Fig. No.
			T _A = +25°C C _L = 50 pF		T _A = -55°C to +125°C C _L = 50 pF	T _A = -40°C to +85°C C _L = 50 pF		
			Typ	Guaranteed Minimum				
t _s (H) t _s (L)	Setup Time D _n to CP	5.0	3.0 3.0	2.0 2.5	3.5 3.5	2.0 2.5	ns	2-7
t _h	Hold Time, HIGH or LOW D _n to CP	5.0	0	1.0	1.5	1.0	ns	2-7
t _w	CP Pulse Width HIGH or LOW	5.0	4.0	3.0	5.0	3.5	ns	2-3
t _w	$\overline{\text{MR}}$ Pulse Width, LOW	5.0	4.0	3.0	5.0	4.0	ns	2-3
t _{rec}	Recovery Time, $\overline{\text{MR}}$ to CP	5.0	0	0	1.5	0	ns	2-3,7

*Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C _{IN}	Input Capacitance	4.5	pF	V _{CC} = 5.0V
C _{PD}	Power Dissipation Capacitance	45.0	pF	V _{CC} = 5.0V